

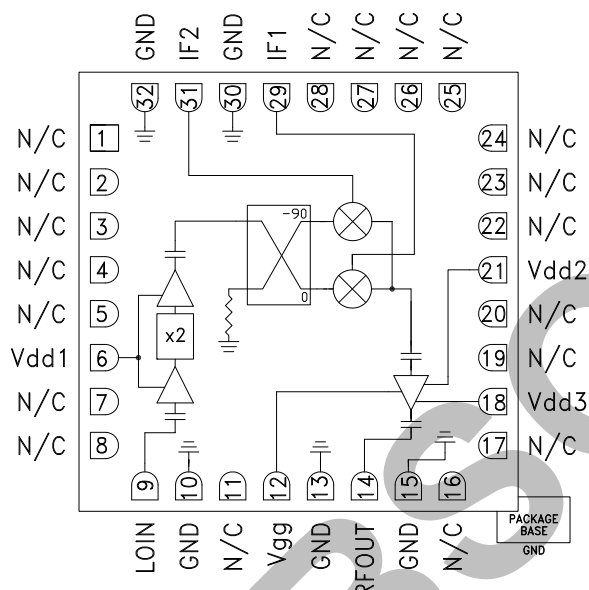
GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz

## Typical Applications

The HMC815LC5 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radios
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

## Functional Diagram



## Features

- High Conversion Gain: 12 dB
- Sideband Rejection: -20 dBc
- 2 LO to RF Isolation: 10 dB
- Output IP3: +27 dBm
- 32 Lead 5x5mm SMT Ceramic Package: 25mm<sup>2</sup>

## General Description

The HMC815LC5 is a compact GaAs MMIC I/Q upconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 12 dB and sideband rejection of -20 dBc. The HMC815LC5 utilizes a driver amplifier preceded by an I/Q mixer where the LO is driven by an active x2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC815LC5 is a much smaller alternative to hybrid style single sideband upconverter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

## Electrical Specifications,

$T_A = +25^\circ\text{C}$ ,  $IF = 2500\text{ MHz}$ ,  $LO = +4\text{ dBm}$ ,  $V_{dd1}, 2, 3 = +4.5\text{V}$ ,  $I_{dd2} + I_{dd3} = 270\text{ mA}$  [1][3]

Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF		21 - 27		GHz
Frequency Range, LO		10.5 - 14.5		GHz
Frequency Range, IF		DC - 3.75		GHz
Conversion Gain	7	12		dB
Sideband Rejection		-20		dBc
1 dB Compression (Output)	17	20		dBm
2 LO to RF Isolation		10		dB
2 LO to IF Isolation [2]		15		dB
IP3 (Output)		27		dBm
Supply Current Idd1		95	120	mA
Supply Current Idd2 + Idd3		270	300	mA

[1] Unless otherwise noted all measurements performed with high side LO, IF = 2500 MHz and external 90° IF hybrid.

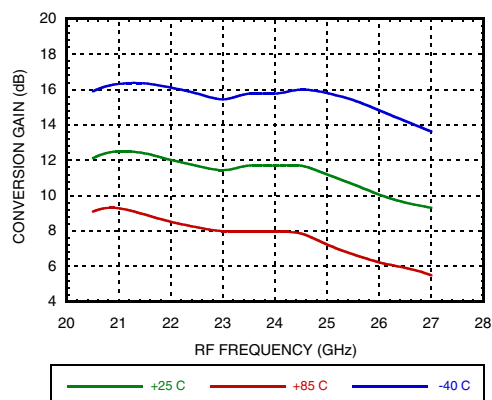
[2] Data taken without external IF hybrid.

[3] Adjust Vgg between -2 to 0V to achieve Idd2 + Idd3 = 270 mA Typical.

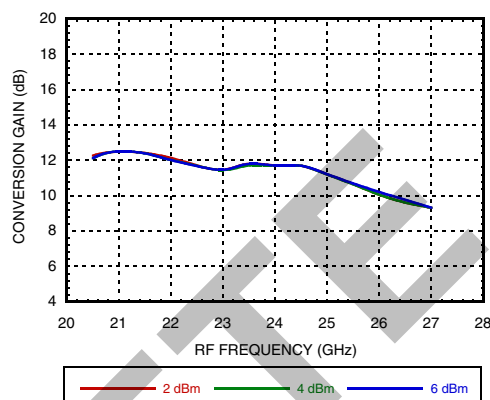


**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**  
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 2500 MHz**

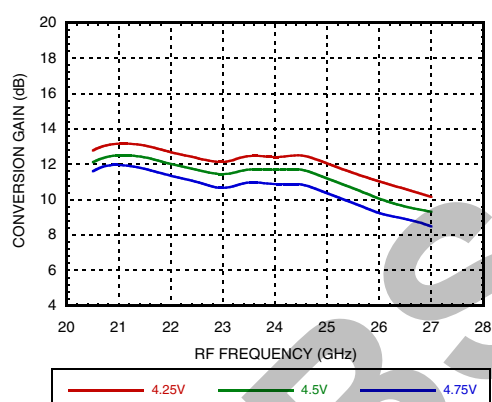
**Conversion Gain, LSB vs. Temperature**



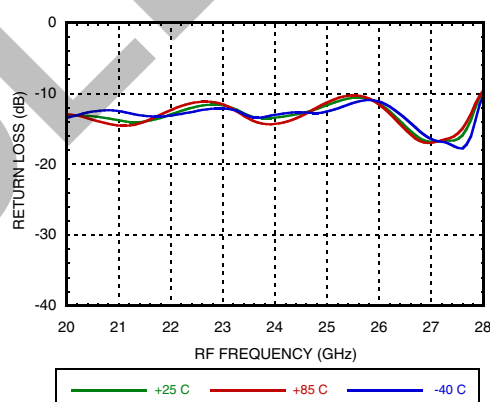
**Conversion Gain, LSB vs. LO Drive**



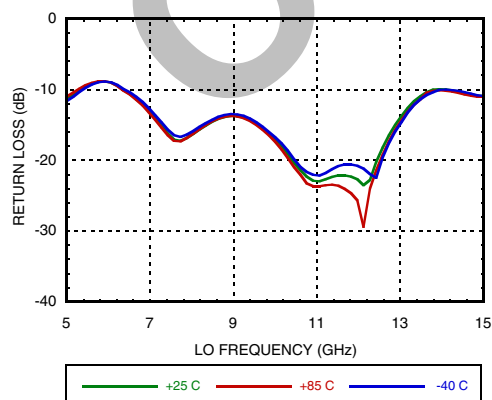
**Conversion Gain, LSB vs. Vdd**



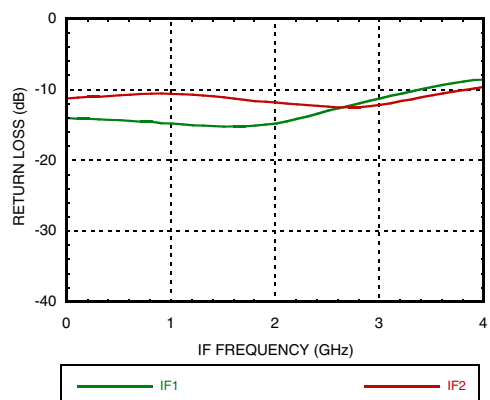
**RF Return Loss vs. Temperature**



**LO Return Loss vs. Temperature**



**IF Return Loss <sup>[1]</sup>**



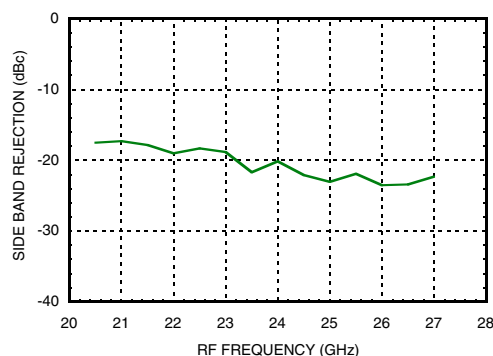
[1] Data taken without external IF hybrid



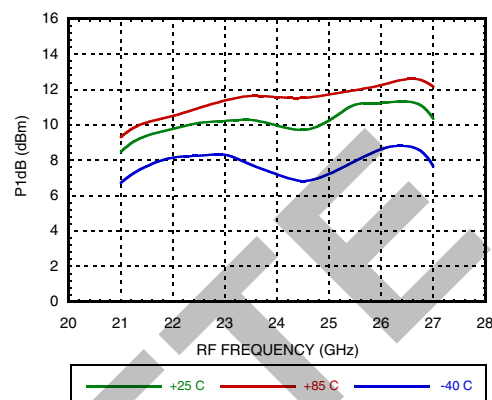
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 2500 MHz**

**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**

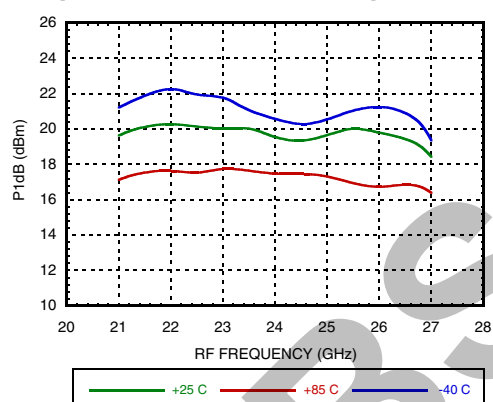
**Side Band Rejection**



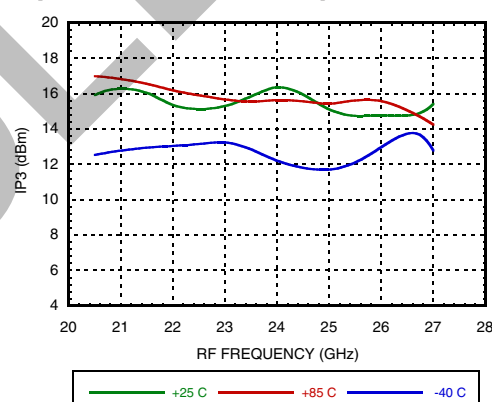
**Input P1dB, LSB vs. Temperature**



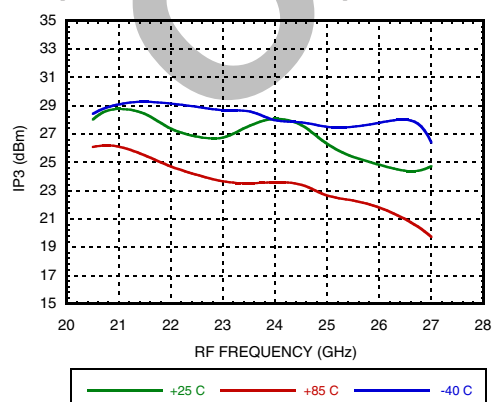
**Output P1dB, LSB vs. Temperature**



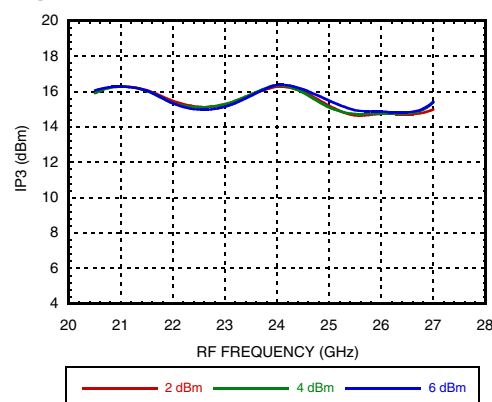
**Input IP3, LSB vs. Temperature**



**Output IP3, LSB vs. Temperature**



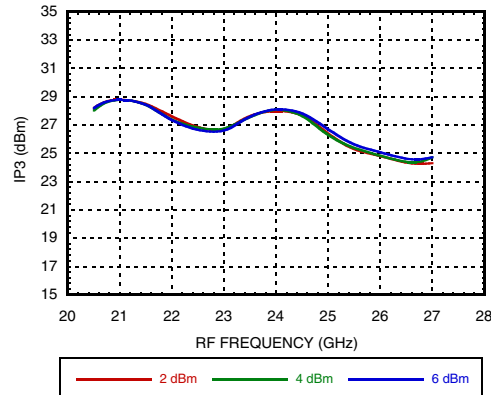
**Input IP3, LSB vs. LO Drive**



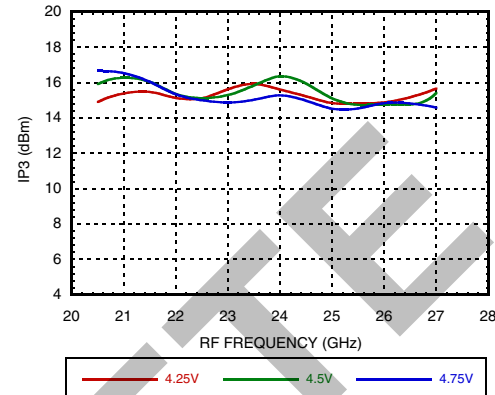


**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**  
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 2500 MHz**

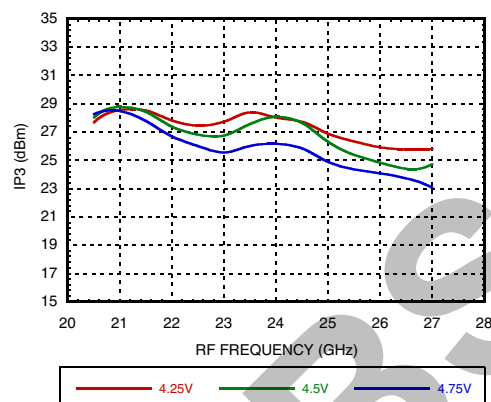
**Output IP3, LSB vs. LO Drive**



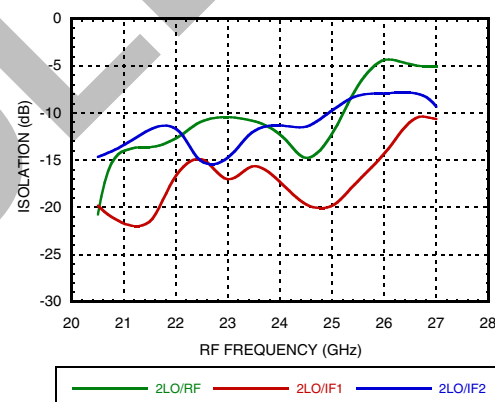
**Input IP3, LSB vs. Vdd**



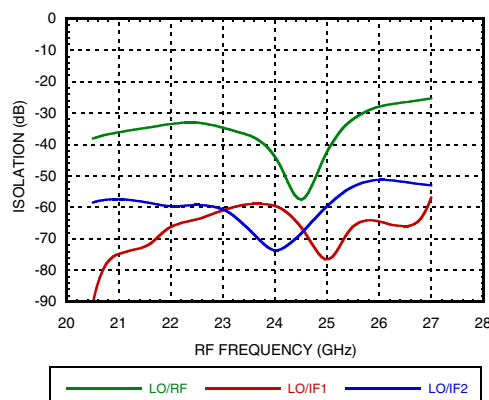
**Output IP3, LSB vs. Vdd**



**Isolations with 2LO <sup>[1]</sup>**



**Isolations with LO <sup>[1]</sup>**



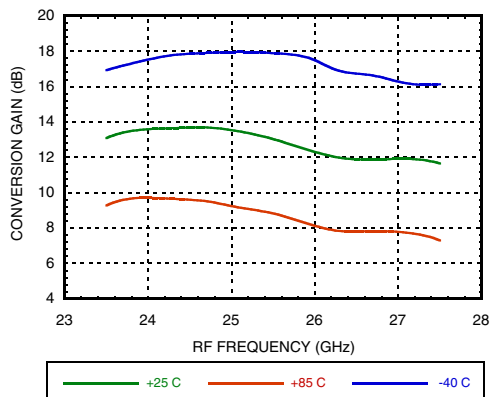
[1] Data taken without external IF hybrid



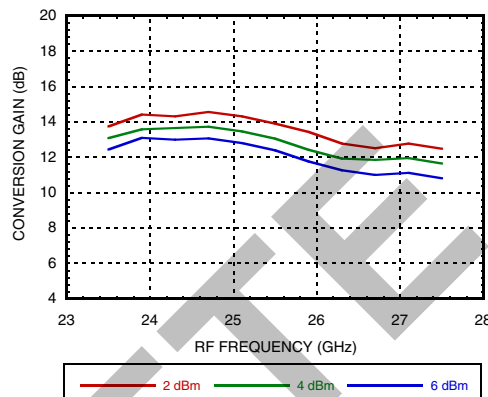
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 2500 MHz**

## GaAs MMIC I/Q UPCONVERTER 21 - 27 GHz

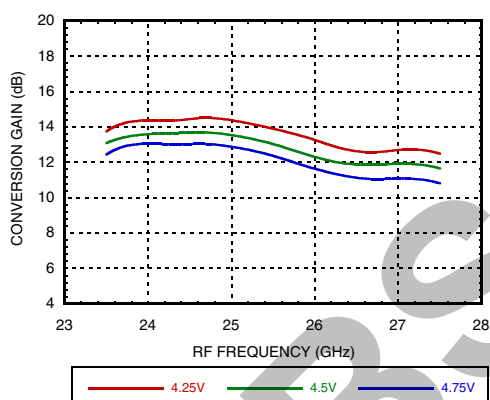
**Conversion Gain, USB vs. Temperature**



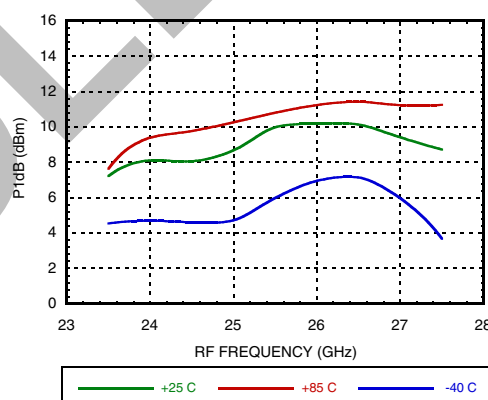
**Conversion Gain, USB vs. LO Drive**



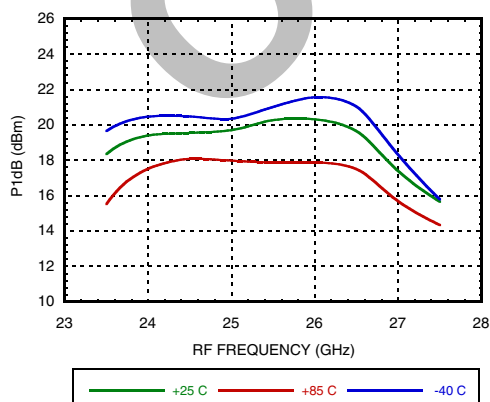
**Conversion Gain, USB vs. Vdd**



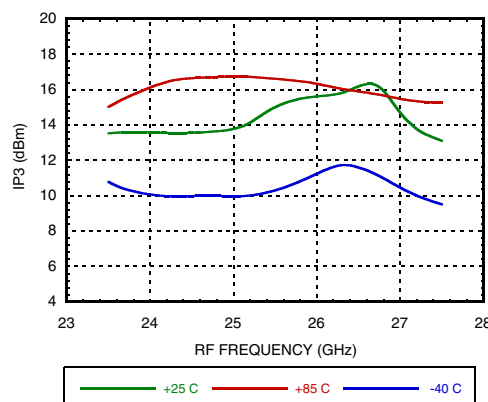
**Input P1dB, USB vs. Temperature**



**Output P1dB, USB vs. Temperature**



**Input IP3, USB vs. Temperature**

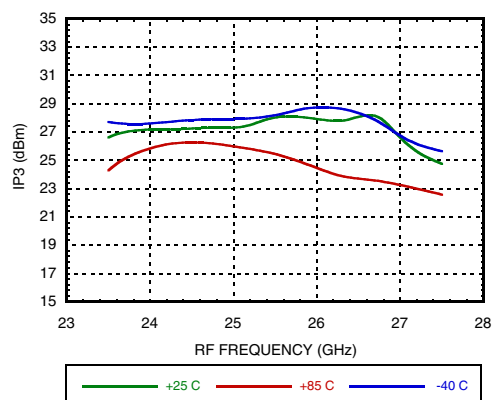




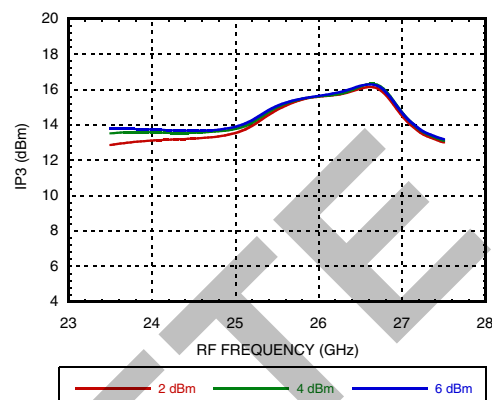
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 2500 MHz**

**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**

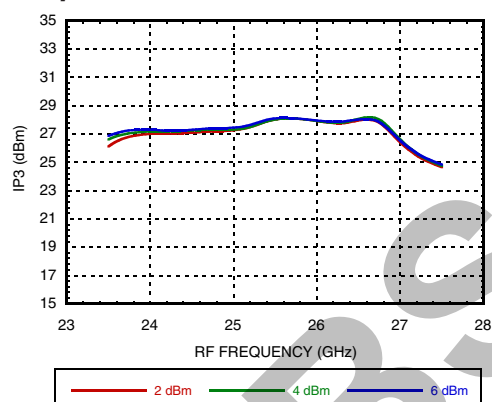
**Output IP3, USB vs. Temperature**



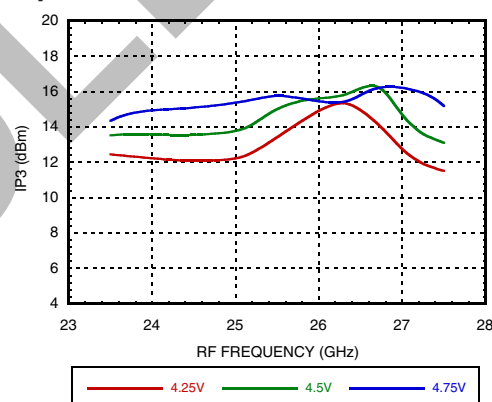
**Input IP3, USB vs. LO Drive**



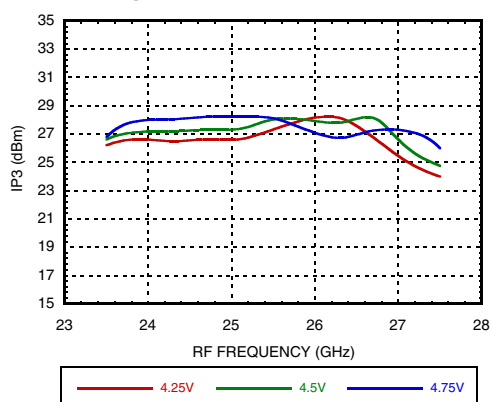
**Output IP3, USB vs. LO Drive**



**Input IP3, USB vs. Vdd**



**Output IP3, USB vs. Vdd**

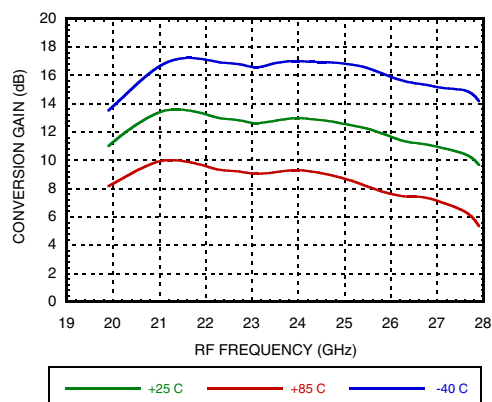




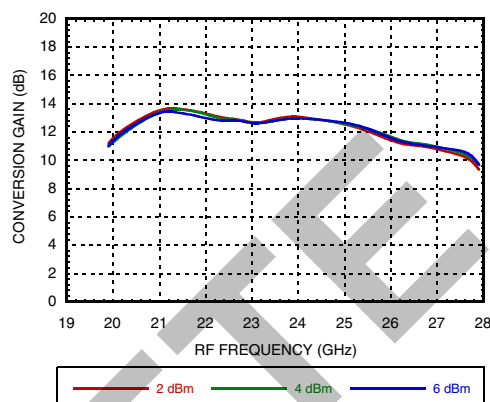
**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**

*Data Taken as SSB Upconverter with External IF Hybrid, IF = 100 MHz*

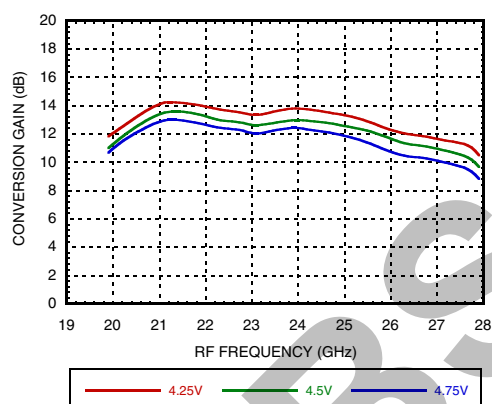
**Conversion Gain, LSB vs. Temperature**



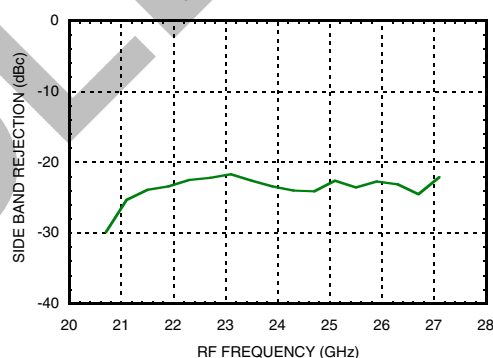
**Conversion Gain, LSB vs. LO Drive**



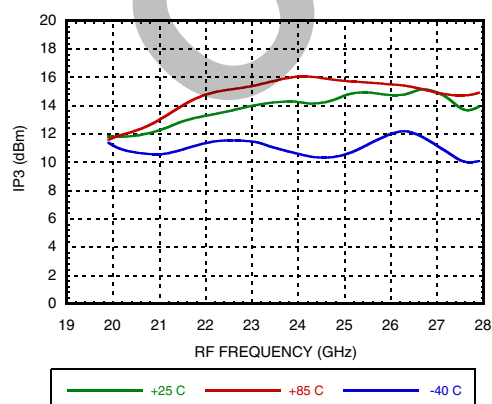
**Conversion Gain, LSB vs. Vdd**



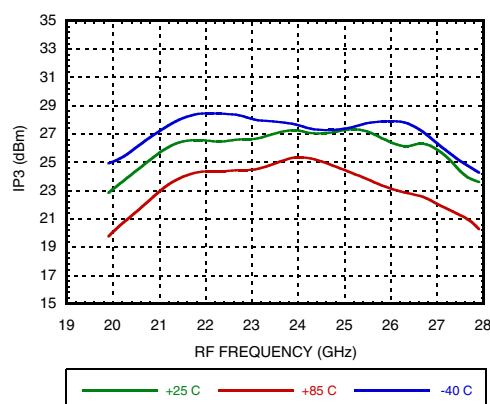
**Sideband Rejection**



**Input IP3, LSB vs. Temperature**



**Output IP3, LSB vs. Temperature**

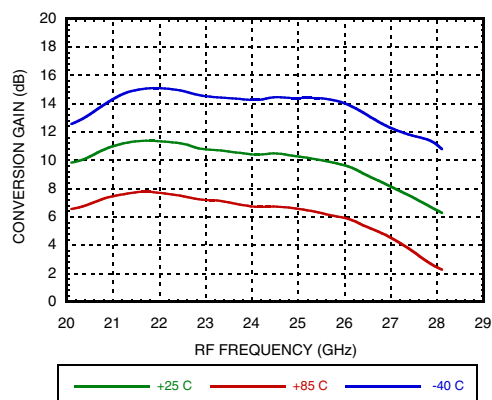




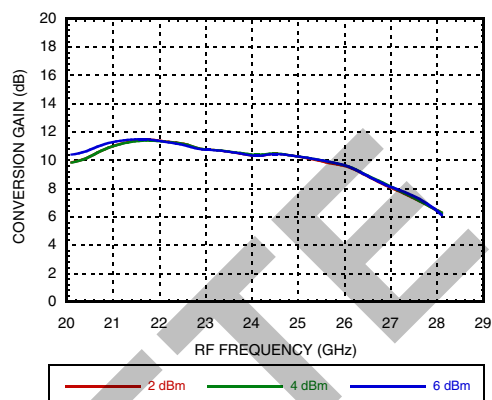
**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**

*Data Taken as SSB Upconverter with External IF Hybrid, IF = 100 MHz*

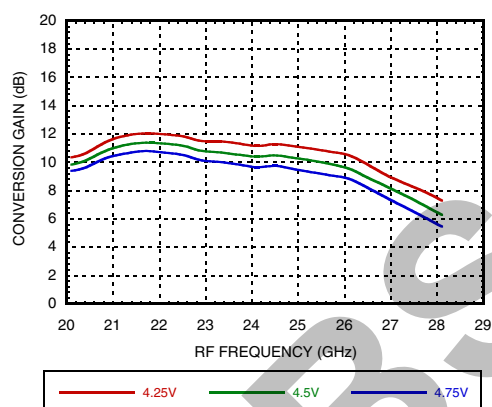
**Conversion Gain, USB vs. Temperature**



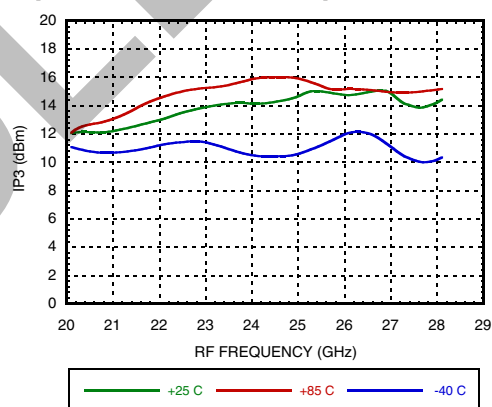
**Conversion Gain, USB vs. LO Drive**



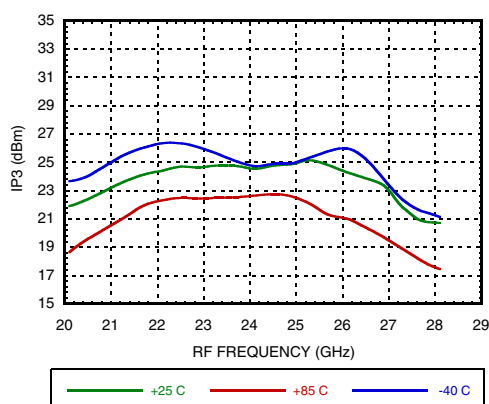
**Conversion Gain, USB vs. Vdd**



**Input IP3, USB vs. Temperature**



**Output IP3, USB vs. Temperature**



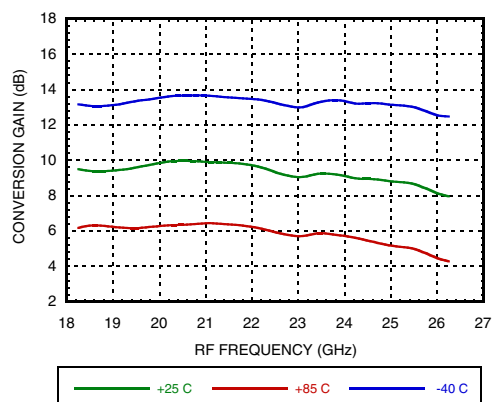




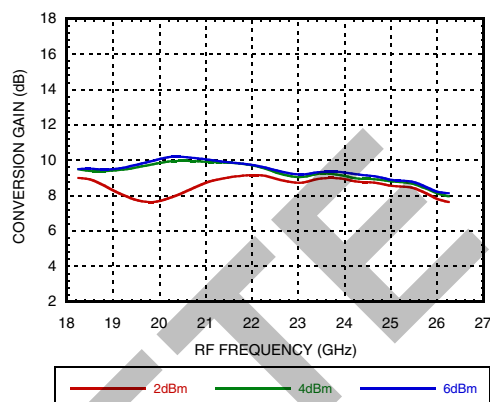
**Data Taken as SSB Upconverter with External IF Hybrid, IF = 3750 MHz**

**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**

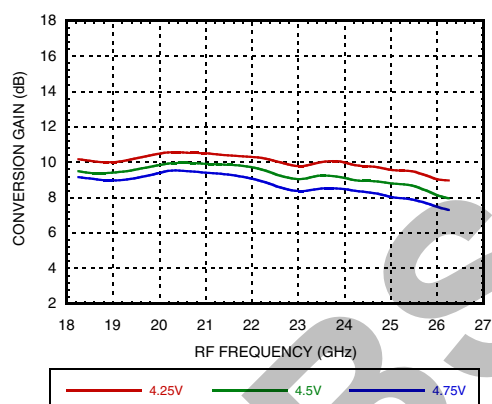
**Conversion Gain, LSB vs. Temperature**



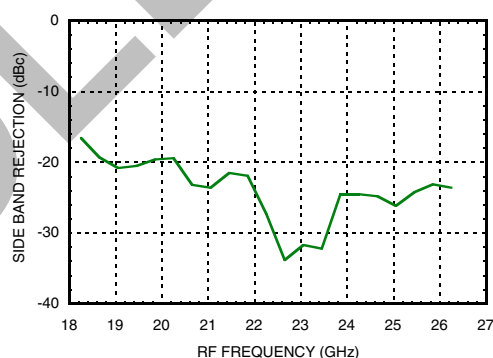
**Conversion Gain, LSB vs. LO Drive**



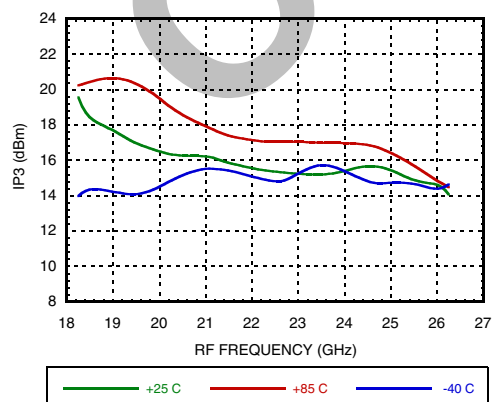
**Conversion Gain, LSB vs. Vdd**



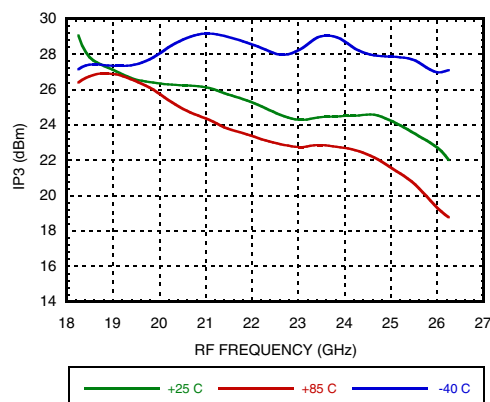
**Sideband Rejection**



**Input IP3, LSB vs. Temperature**



**Output IP3, LSB vs. Temperature**

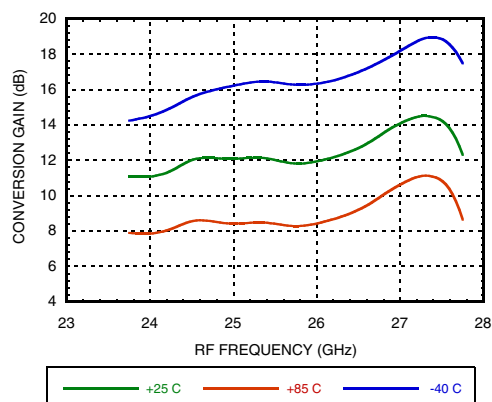




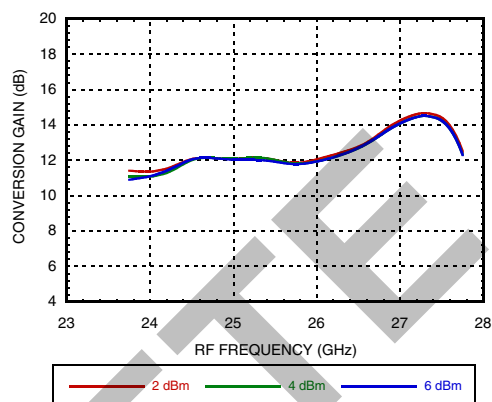
**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**

*Data Taken as SSB Upconverter with External IF Hybrid, IF = 3750 MHz*

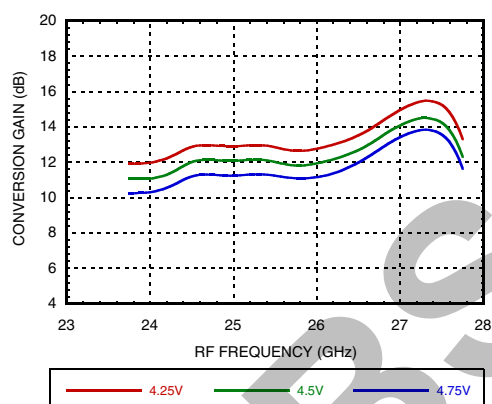
**Conversion Gain, USB vs. Temperature**



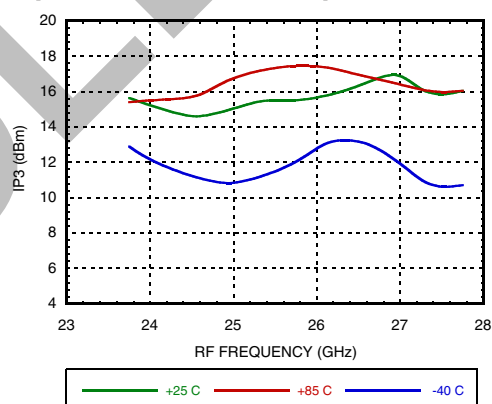
**Conversion Gain, USB vs. LO Drive**



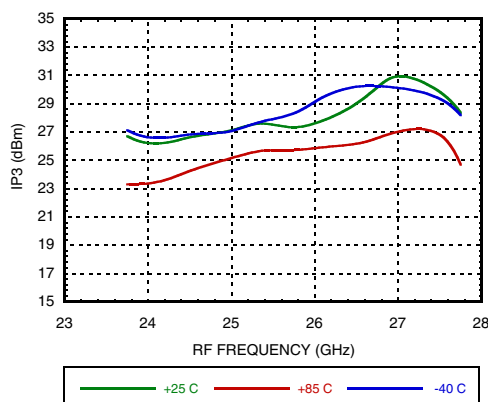
**Conversion Gain, USB vs. Vdd**



**Input IP3, USB vs. Temperature**



**Output IP3, USB vs. Temperature**




**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**
**MxN Spurious Outputs [1][2]**

mIF	nLO			
	0	1	2	3
0	xx	38	6	23
1	66	38	0	38
2	59	44	50	59
3	86	80	58	xx

IF = 2.5 GHz @ -10 dBm

LO = 11 GHz @ 4 dBm

**MxN Spurious Outputs [1][2]**

mIF	nLO			
	0	1	2	3
0	xx	35	9	24
1	71	37	0	38
2	58	44	42	65
3	92	79	56	xx

IF = 2.5 GHz @ -10 dBm

LO = 11.25 GHz @ 4 dBm

**MxN Spurious Outputs [1][2]**

mIF	nLO			
	0	1	2	3
0	xx	36	15	26
1	xx	42	0	47
2	61	53	72	77
3	xx	76	57	xx

IF = 2.5 GHz @ -10 dBm

LO = 11.5 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	xx	xx	61	84
-2	59	92	46	63
-1	xx	74	0	54
0	xx	31	9	26

IF = 2.5 GHz @ -10 dBm

LO = 11.75 GHz @ 4 dBm

**MxN Spurious Outputs [1][2]**

mIF	nLO			
	0	1	2	3
0	xx	31	9	26
1	xx	42	0	65
2	59	62	53	xx
3	xx	83	57	xx

IF = 2.5 GHz @ -10 dBm

LO = 11.75 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
0	xx	28	9	31
1	xx	44	0	61
2	60	62	57	xx
3	xx	86	57	xx

IF = 2.5 GHz @ -10 dBm

LO = 12 GHz @ 4 dBm

[1] Data taken without external IF hybrid

[2] All values in dBc below RF power level (2LO + IF) USB

[3] All values in dBc below RF power level (2LO - IF) LSB


**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**
**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	xx	xx	60	85
-2	61	xx	47	77
-1	80	79	0	64
0	xx	28	9	35

IF = 2.5 GHz @ -10 dBm  
LO = 12.25 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	88	xx	56	xx
-2	60	93	51	86
-1	71	71	0	69
0	xx	28	4	34

IF = 2.5 GHz @ -10 dBm  
LO = 12.75 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	89	xx	55	72
-2	61	96	46	72
-1	71	83	0	70
0	xx	38	7	29

IF = 2.5 GHz @ -10 dBm  
LO = 13.25 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	xx	xx	54	xx
-2	62	xx	63	79
-1	xx	30	6	xx
0	xx	31	6	xx

IF = 2.5 GHz @ -10 dBm  
LO = 13.75 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	xx	xx	54	xx
-2	62	82	42	73
-1	73	57	0	xx
0	xx	20	-3	xx

IF = 2.5 GHz @ -10 dBm  
LO = 14.25 GHz @ 4 dBm

**MxN Spurious Outputs [1][3]**

mIF	nLO			
	0	1	2	3
-3	xx	xx	53	xx
-2	61	55	0	74
-1	65	55	0	xx
0	xx	16	-3	xx

IF = 2.5 GHz @ -10 dBm  
LO = 14.75 GHz @ 4 dBm

[1] Data taken without external IF hybrid

[2] All values in dBc below RF power level (2LO + IF) USB

[3] All values in dBc below RF power level (2LO - IF) LSB


**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**
**Absolute Maximum Ratings**

Drain Bias Voltage (Vdd1, 2, 3)	5.5V
Gate Bias Voltage (Vgg)	-3V to 0V
IF Input Power (IF1, IF2)	20 dBm
LO Drive (LO IN)	+13 dBm
Channel Temperature	170 °C
Continuous P <sub>diss</sub> (T = 85°C) (derate 21.4 mW/°C above 85°C)	1.82 W
Thermal Resistance (channel to ground paddle)	46.7 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 0, Passed 150V

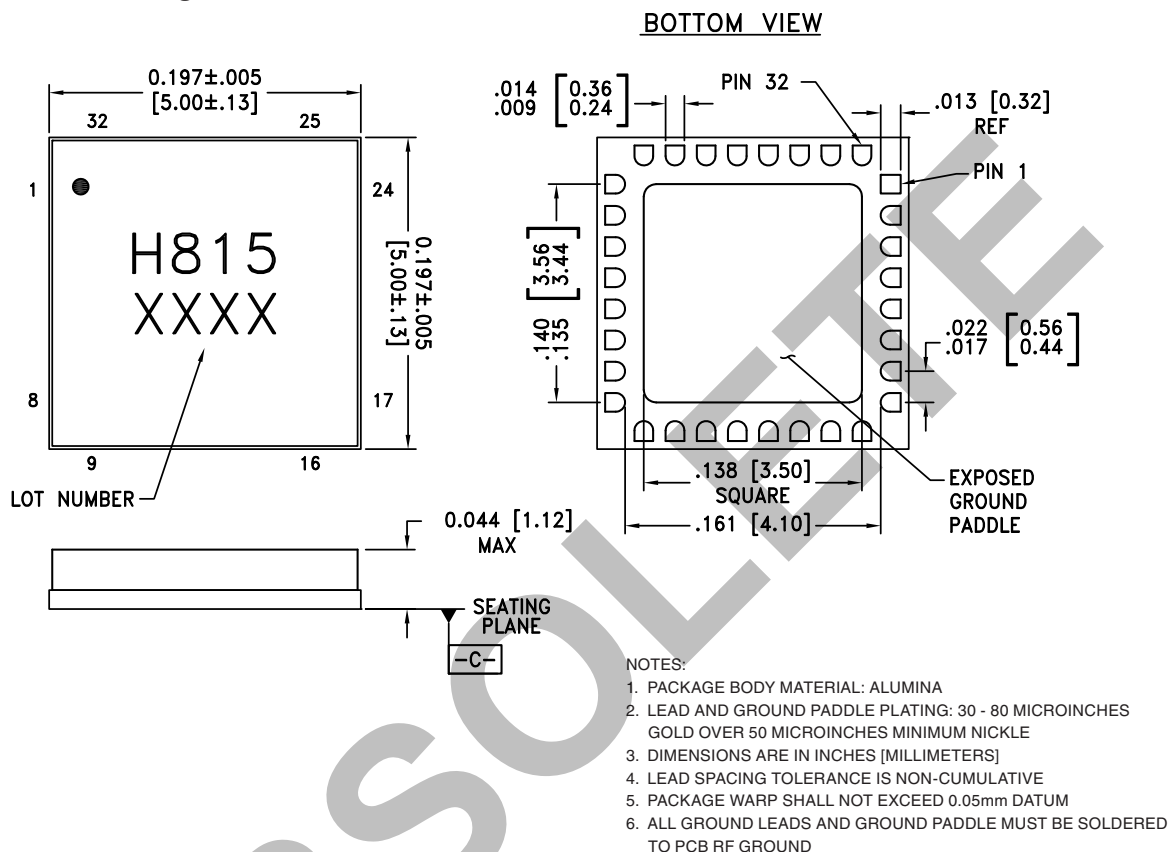
**Harmonics of LO @ RF Output**

LO Freq. (GHz)	nLO Spur @ IF Port		
	1	2	3
11.00	38	6	23
11.25	35	9	24
11.50	36	15	26
11.75	31	9	26
12.00	28	9	31
12.25	28	9	35
12.75	28	4	34
13.25	38	7	29
13.75	30	6	xx
14.24	20	-3	xx
14.75	16	-3	xx

LO Power = +4 dBm

All values in dBc below input LO level measured at RF port.


**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**


**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**
**Outline Drawing**

**Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC815LC5	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H815 XXXX

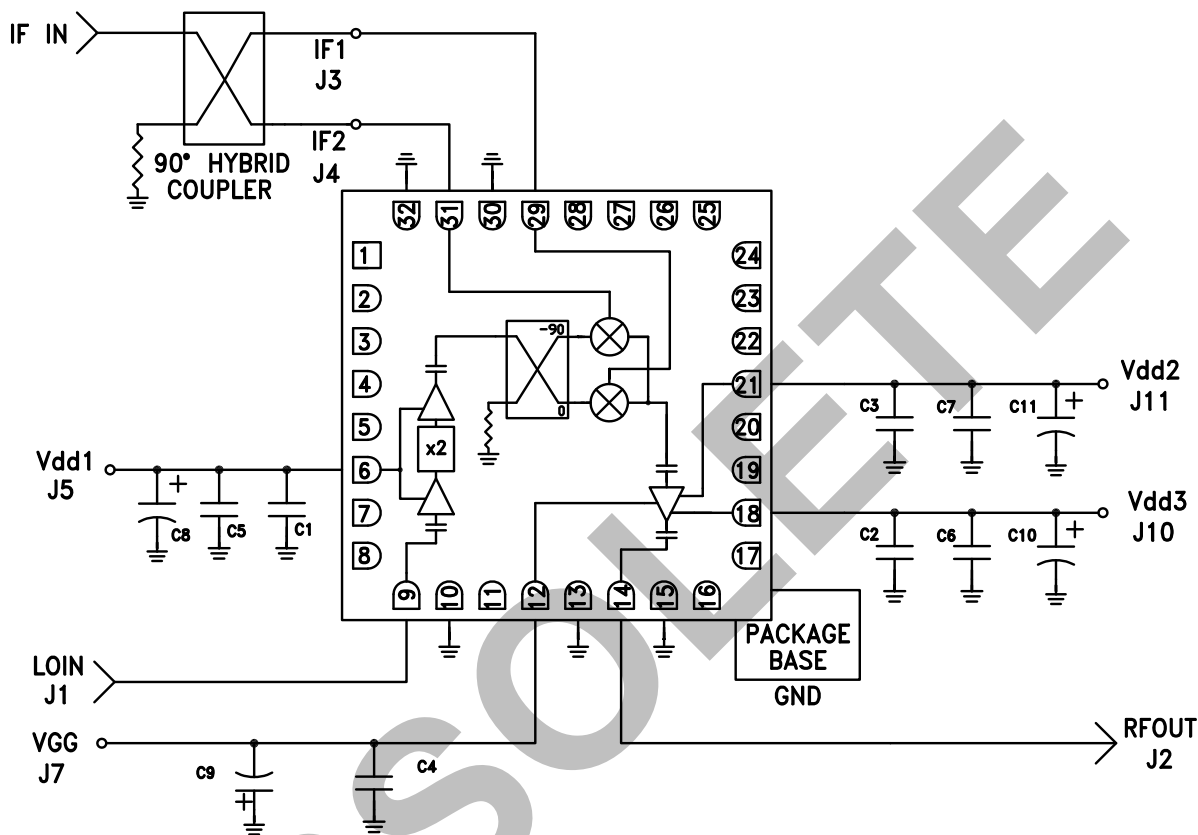
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



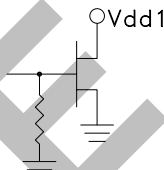
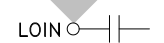
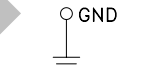
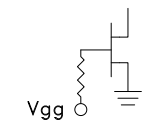
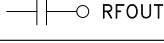
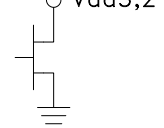
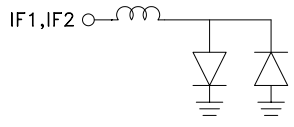
**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**

**Typical Application**



C1 - C3	100 pF
C4 - C7	1000 pF
C8 - C11	2.2 $\mu$ F


**GaAs MMIC I/Q UPCONVERTER**  
**21 - 27 GHz**
**Pin Descriptions**

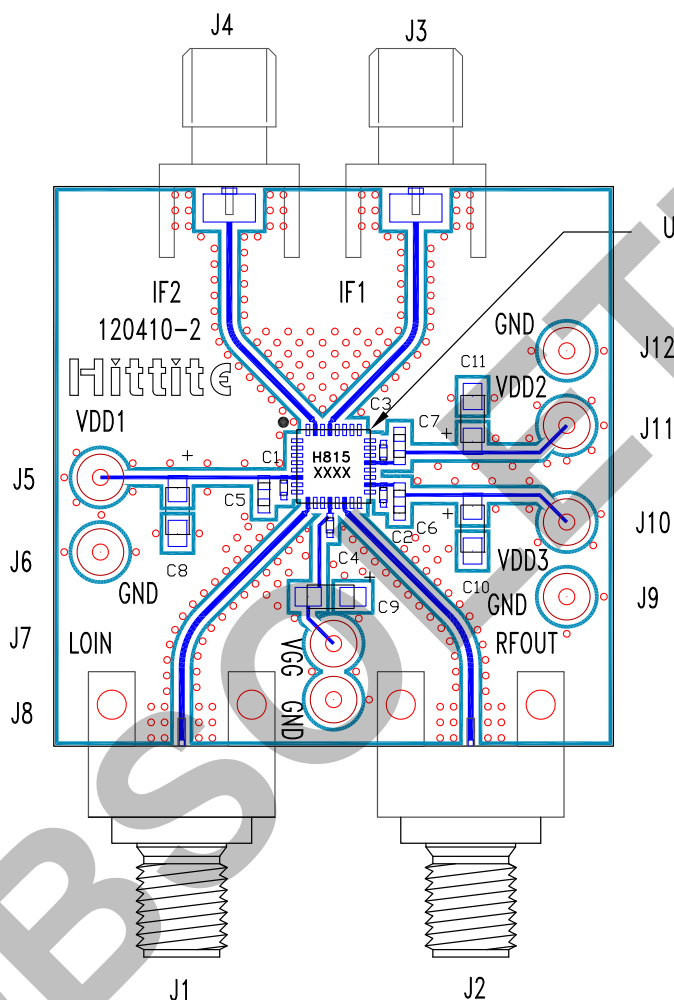
Pin Number	Function	Description	Interface Schematic
1 - 5, 7, 8, 11, 16, 17, 19, 20, 22 - 28	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
6	Vdd1	Power supply voltage for x2 multiplier. See application circuit for required external components.	
9	LOIN	This pin is AC coupled and matched to 50 Ohms.	
10, 13, 15, 30, 32	GND	These pins and package bottom must be connected to RF/DC ground.	
12	Vgg	Gate control for RF amplifier, please follow "MMIC Amplifier Biasing Procedure" application note. See application circuit for required external components.	
14	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
18, 21	Vdd3, Vdd2	Power supply voltage for RF amplifier. See application circuit for required external components.	
29	IF1	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should be used. For operation to DC this pin must not source/sink more than 3mA of current or part non function and possible part failure will result.	
31	IF2		





**GaAs MMIC I/Q UPCONVERTER  
21 - 27 GHz**

**Evaluation PCB**



**List of Materials for Evaluation PCB 120412 <sup>[1]</sup>**

Item	Description
J1, J2	PCB Mount 2.99mm Connector
J3, J4	PCB Mount SMA Connector
J5 - J12	DC Pin
C1 - C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0402 Pkg.
C5 - C7	1000 pF Capacitor, 0603 Pkg.
C8 - C11	2.2 $\mu$ F Tantalum Capacitor Case A
U1	HMC815LC5 Upconverter
PCB <sup>[2]</sup>	120410 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

OBSOLETE